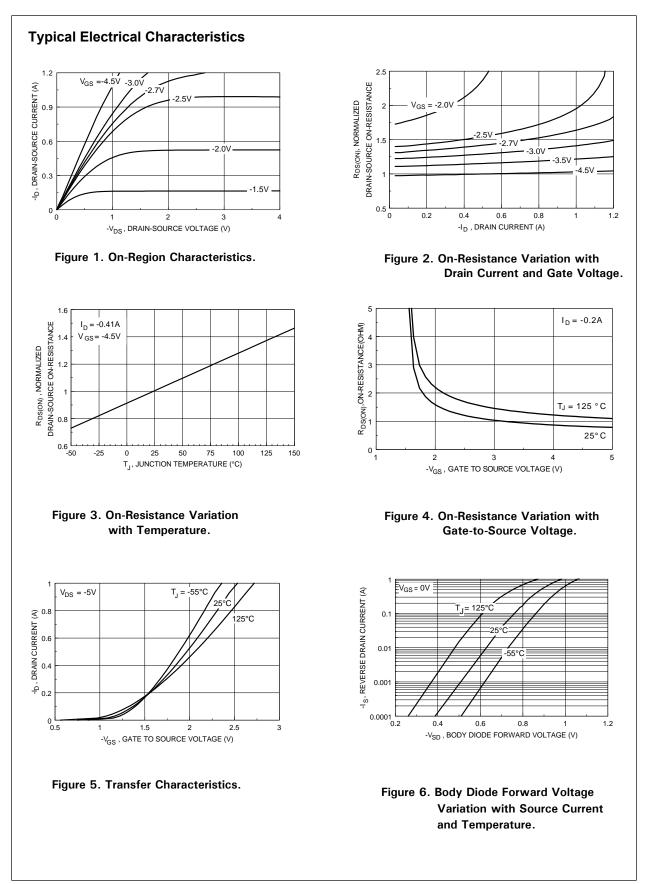


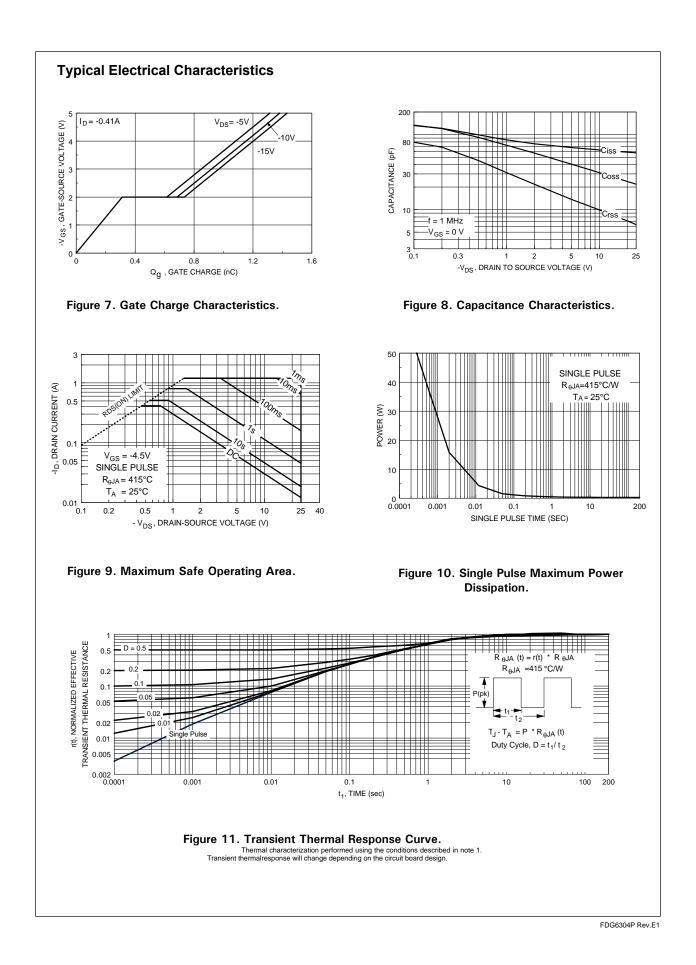
Symbol	Parameter	Conditions	Min	Тур	Max	Units
OFF CHAR	ACTERISTICS	·				
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$	-25			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{D}$ = -250 µA, Referenced to 25°C		-22		mV /°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -20 V, V_{GS} = 0 V$			-1	μA
		T <sub>J</sub> = 55°C			-10	μA
I <sub>GSS</sub>	Gate - Body Leakage Current	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
ON CHARA	CTERISTICS (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.65	-0.82	-1.5	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp.Coefficient	$I_{D}$ = -250 µA, Referenced to 25°C		2		mV /°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -0.41 A		0.85	1.1	Ω
. ,		T <sub>J</sub> =125°C		1.2	1.9	
		V <sub>GS</sub> = -2.7 V, I <sub>D</sub> = -0.25 A		1.15	1.5	
I <sub>D(ON)</sub>	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$	-1.5			А
9 <sub>FS</sub>	Forward Transconductance	$V_{\rm DS} = -5 \text{ V}, \ \text{I}_{\rm D} = -0.41 \text{ A}$		0.9		S
DYNAMIC C	HARACTERISTICS					
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		62		pF
C <sub>oss</sub>	Output Capacitance	f = 1.0 MHz		34		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			10		pF
SWITCHING	CHARACTERISTICS (Note 2)		-			
t <sub>D(on)</sub>	Turn - On Delay Time	$V_{DD} = -5 \text{ V}, \ \text{I}_{D} = -0.5 \text{ A}, \\ V_{GS} = -4.5 \text{ V}, \ \text{R}_{GEN} = 6 \Omega$		7	15	ns
ţ,	Turn - On Rise Time			8	16	ns
t <sub>D(off)</sub>	Turn - Off Delay Time			55	80	ns
t <sub>r</sub>	Turn - Off Fall Time			35	60	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = -5 V$ , $I_D = -0.41 A$ ,		1.1	1.5	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS}^{0} = -4.5 V^{0}$		0.31		nC
$Q_{gd}$	Gate-Drain Charge			0.29		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS AND MAXIM	UM RATINGS				
I <sub>s</sub>	Maximum Continuous Source Current				-0.25	А
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = -0.25 A$ (Note 2)		-0.85	-1.2	V

Notes:

1. R<sub>pk</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>pk</sub> is guaranteed by design while  $R_{hch}$  is determined by the user's board design.  $R_{hch} = 415^{\circ}$ C/W on minimum pad mounting on FR-4 board in still air. 2. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2.0%.



FDG6304P Rev.E1



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